1-A Quad-HBD (Quad-Half-Bridge Driver) TLE4208G

AEC Qualified

RoHS

Overview

PG-DSO-28-24

Features

- Driver for up to 3 motors
- Delivers up to 0.8 A continuous
- Optimized for DC motor management applications
- Very low current consumption in stand-by (Inhibit) mode
- Low saturation voltage; typ.1.2 V total @ 25 °C; 0.4 A
- Output protected against short circuit
- Error flag diagnosis
- Overvoltage lockout and diagnosis
- Undervoltage lockout
- CMOS/TTL compatible inputs with hysteresis
- No crossover current
- Internal clamp diodes
- Overtemperature protection with hysteresis and diagnosis
- Enhanced power DSO-Package
- Green Product (RoHS compliant)
- AEC Qualified

Type	Ordering Code	Package
TLE4208G	on request	PG-DSO-28-24

Description

The TLE4208G is a protected **Quad-H**alf-**B**ridge-**D**river designed specially for automotive and industrial motion control applications.

The part is built using Infineons bipolar high voltage power technology DOPL.

In a cascade configuration up to three actuators (DC motors) can be connected between the four half-bridges. These four half-bridges are configured as 2 dual-half-bridges, which are supplied and controlled separately. Operation modes forward (cw), reverse (ccw), brake and high impedance are invoked from a standard interface.

The standard enhanced power PG-DSO-28-24 package meets the application requirements and saves PCB-board space and costs. Moreover the package is RoHS compliant.

Furthermore the built-in features like diagnosis, over- and undervoltage-lockout, short-circuit protection, over-temperature protection and the very low quiescent current in stand-by mode will open a wide range of automotive and industrial applications.

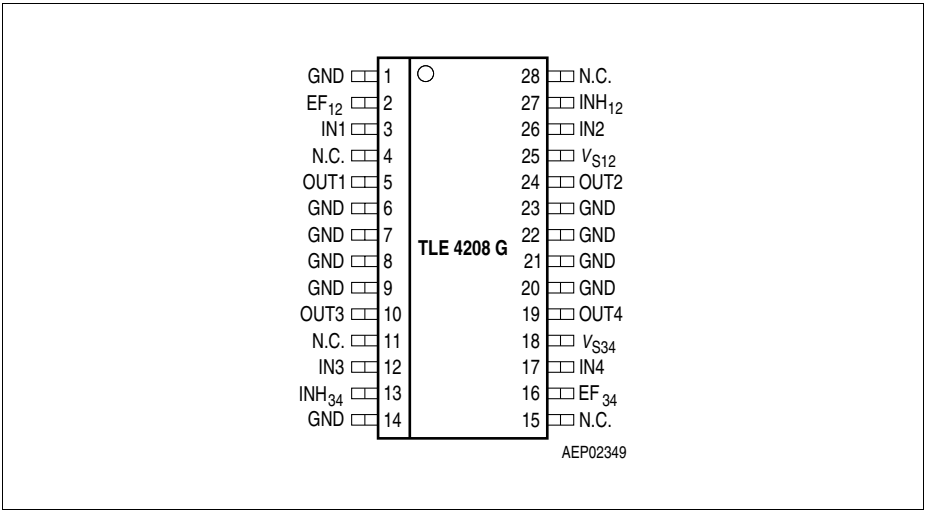


Figure 1 **Pin Configuration** (top view)

Pin Definitions and Functions

Pin No.	Symbol	Function
1, 6, 7, 8, 9, 14, 20, 21, 22, 23	GND	**Ground;** negative reference potential for blocking capacitor
2	EF_{12}	**Error Flag output of half-bridges 1and 2;** open collector; low = error
3	IN1	**Input channel of half-bridge 1;** controls OUT1
4, 11, 15, 28	N.C.	**Not connected**
5	OUT1	**Power output of half-bridge 1;** short circuit protected; with integrated clamp diodes
10	OUT3	**Power output of half-bridge 3;** short-circuit protected; with integrated clamp diodes
12	IN3	**Input channel of half-bridge 3;** controls OUT3
13	INH_{34}	**Inhibit input of half-bridges 3 and 4;** low = half-bridges 3 and 4 in stand-by
16	EF_{34}	**Error Flag output of half-bridges 3 and 4;** open collector; low = error
17	IN4	**Input channel of half-bridge 4;** controls OUT4
18	V_{S34}	**Power supply voltage of half-bridges 3 and 4;** positive reference potential for blocking capacitor
19	OUT4	**Power output of half-bridge 4;** short circuit protected; with integrated clamp diodes
24	OUT2	**Power-output of half-bridge 2;** short circuit protected; with integrated clamp diodes
25	V_{S12}	**Power supply voltage of half-bridges 1 and 2;** positive reference potential for blocking capacitor
26	IN2	**Input channel of half-bridge 2;** controls OUT2
27	INH_{12}	**Inhibit input of half-bridges 1and 2;** low = half-bridges 1 and 2 in stand-by

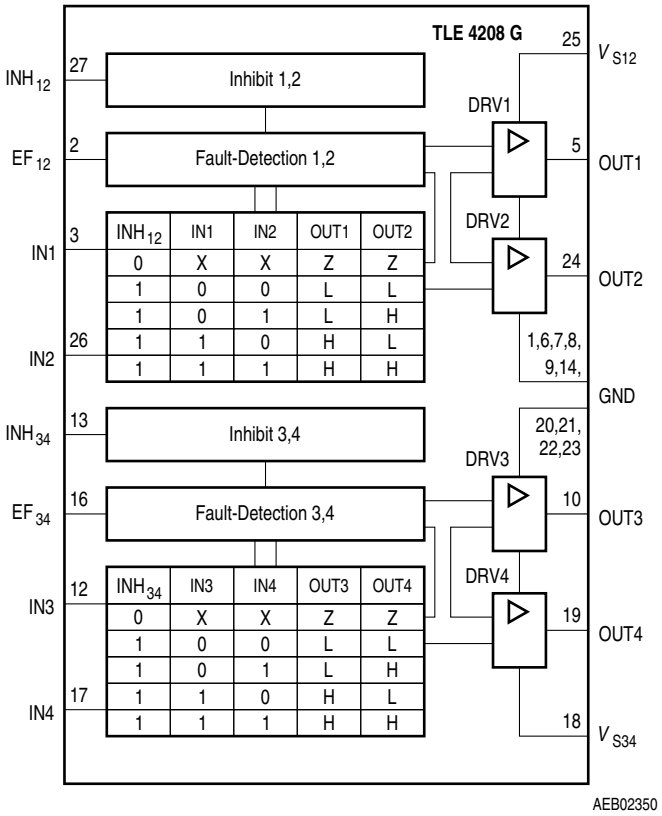


Figure 2 Block Diagram

Input Logic

Functional Truth Table of Halfbridge 1 and 2

INH_{12}	IN1	IN2	OUT1	OUT2	Mode
0	X	X	Z	Z	Stand-By
1	0	0	L	L	Brake LL
1	0	1	L	H	CW
1	1	0	H	L	CCW
1	1	1	H	H	Brake HH

Note: Half-Bridge 1 and 2 connected to a full-bridge

Functional Truth Table of Half-Bridge 3 and 4

INH_{34}	IN3	IN4	OUT3	OUT4	Mode
0	X	X	Z	Z	Stand-By
1	0	0	L	L	Brake LL
1	0	1	L	H	CW
1	1	0	H	L	CCW
1	1	1	H	H	Brake HH

IN: 0 = Logic LOW
1 = Logic HIGH
X = don't care

OUT: Z = Output in tristate condition
L = Output in sink condition
H = Output in source condition

Note: Half-Bridge 3 and 4 connected to a full-bridge

Diagnosis

EF_{12}	EF_{34}	Error
1	1	no error
0	1	over temperature of half-bridge 1 and 2 or
0	1	over voltage of half-bridge 1 and 2
1	0	over temperature of half-bridge 3 and 4 or
1	0	over voltage of half-bridge 3 and 4
0	0	over temperature of all half-bridges or
0	0	over voltage of all half-bridges

Electrical Characteristics

Absolute Maximum Ratings

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		
Voltages					
Supply voltage	V_{S12}, V_{S34}	– 0.3	45	V	–
Supply voltage	V_{S12}, V_{S34}	– 1	–	V	t < 0.5 s; I_{S12}, I_{S34} > – 2 A
Logic input voltages (IN1; IN2; INH_{12}; IN3; IN4; INH_{34})	V_I	– 5	20	V	0V < V_{S12}, V_{S34} < 45 V
Logic output voltage (EF_{12}; EF_{34})	V_{EF12}, V_{EF34}	– 0.3	20	V	0 V < V_{S12}, V_{S34} < 45 V
Currents					
Output current (cont.)	I_{OUT1-4}	–	–	A	internally limited
Output current (peak)	I_{OUT1-4}	–	–	A	internally limited
Output current (diode)	I_{OUT1-4}	–1	1	A	–
Output current (EF)	$I_{EF12-34}$	–2	5	mA	–
Temperatures					
Junction temperature	T_j	– 40	150	°C	–
Storage temperature	T_{stg}	– 50	150	°C	–
Thermal Resistances					
Junction pin	$R_{thj-pin}$	–	25	K/W	measured to pin 7
Junction ambient	R_{thjA}	–	65	K/W	–

Note: Maximum ratings are absolute ratings; exceeding any one of these values may cause irreversible damage to the integrated circuit.

Operating Range

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		
Supply voltage	V_{S12}, V_{S34}	$V_{UV\ OFF}$	18	V	After V_{S12}, V_{S34} rising above $V_{UV\ ON}$
Supply voltage increasing	V_{S12}, V_{S34}	– 0.3	$V_{UV\ ON}$	V	Outputs in tristate
Supply voltage decreasing	V_{S12}, V_{S34}	– 0.3	$V_{UV\ OFF}$	V	Outputs in tristate
Logic input voltages (IN1; IN2; INH_{12}; IN3; IN4; INH_{34})	V_I	– 2	18	V	–
Junction temperature	T_j	– 40	150	°C	–

Note: In the operating range the functions given in the circuit description are fulfilled.

Electrical Characteristics

8 V < V_{S12} = V_{S34} < 18 V; INH_{12} = INH_{34} = HIGH; I_{OUT1-4} = 0 A; – 40 °C < T_j < 150 °C; unless otherwise specified

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
Current Consumption						
INH_{12} = INH_{34} = LOW						
Quiescent current	I_S	–	–	100	µA	$I_S = I_{S12} + I_{S34}$
Quiescent current	I_S	–	20	40	µA	$I_S = I_{S12} + I_{S34}$; $V_{S12} = V_{S34}$ = 13.2 V; T_j = 25 °C
INH_{12} = HIGH and INH_{34} = LOW or INH_{12} = LOW and INH_{34} = HIGH						
Supply current	I_{S12}, I_{S34}	–	10	20	mA	–
Supply current	I_{S12}, I_{S34}	–	–	30	mA	$I_{OUT1/3}$ = 0.4 A $I_{OUT2/4}$ = – 0.4 A
Supply current	I_{S12}, I_{S34}	–	–	50	mA	$I_{OUT1/3}$ = 0.8 A $I_{OUT2/4}$ = – 0.8 A
Over- and Under Voltage Lockout						
UV Switch ON voltage	$V_{UV\ ON}$	–	6.5	7.5	V	V_{S12}, V_{S34} increasing
UV Switch OFF voltage	$V_{UV\ OFF}$	5	6	–	V	V_{S12}, V_{S34} decreasing
UV ON/OFF hysteresis	$V_{UV\ HY}$	–	0.5	–	V	$V_{UV\ ON} - V_{UV\ OFF}$
OV Switch OFF voltage	$V_{OV\ OFF}$	–	20	24	V	V_{S12}, V_{S34} increasing
OV Switch ON voltage	$V_{OV\ ON}$	18	19.5	–	V	V_{S12}, V_{S34} decreasing
OV ON/OFF hysteresis	$V_{OV\ HY}$	–	0.5	–	V	$V_{OV\ OFF} - V_{OV\ ON}$

Electrical Characteristics (cont'd)

8 V < V_{S12} = V_{S34} < 18 V; INH_{12} = INH_{34} = HIGH; I_{OUT1-4} = 0 A; – 40 °C < T_j < 150 °C; unless otherwise specified

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
Outputs OUT1; OUT2; OUT 3; OUT 4						
Saturation Voltages						
Source (upper) I_{OUT12}, I_{OUT34} = – 0.2 A	$V_{SAT\,U}$	–	0.85	1.15	V	T_j = 25 °C
Source (upper) I_{OUT12}, I_{OUT34} = – 0.4 A	$V_{SAT\,U}$	–	0.90	1.20	V	T_j = 25 °C
Sink (upper) I_{OUT12}, I_{OUT34} = – 0.8 A	$V_{SAT\,U}$	–	1.10	1.50	V	T_j = 25 °C
Sink (lower) I_{OUT12}, I_{OUT34} = 0.2 A	$V_{SAT\,L}$	–	0.15	0.23	V	T_j = 25 °C
Sink (lower) I_{OUT12}, I_{OUT34} = 0.4 A	$V_{SAT\,L}$	–	0.25	0.40	V	T_j = 25 °C
Sink (lower) I_{OUT12}, I_{OUT34} = 0.8 A	$V_{SAT\,L}$	–	0.45	0.75	V	T_j = 25 °C
Total Drop I_{OUT12}, I_{OUT34} = 0.2 A	V_{SAT}	–	1	1.4	V	V_{SAT} = $V_{SAT\,U}$ + $V_{SAT\,L}$
Total Drop I_{OUT12}, I_{OUT34} = 0.4 A	V_{SAT}	–	1.2	1.7	V	V_{SAT} = $V_{SAT\,U}$ + $V_{SAT\,L}$
Total Drop I_{OUT12}, I_{OUT34} = 0.8 A	V_{SAT}	–	1.6	2.5	V	V_{SAT} = $V_{SAT\,U}$ + $V_{SAT\,L}$
Clamp Diodes						
Forward voltage; upper	V_{FU}	–	1	1.5	V	I_F = 0.4 A
Upper leakage current	I_{LKU}	–	–	5	mA	I_F = 0.4 A[1)]
Forward voltage; lower	V_{FL}	–	0.9	1.4	V	I_F = 0.4 A

Notes see page 11.

Electrical Characteristics (cont'd)

8 V < V_{S12} = V_{S34} < 18 V; INH_{12} = INH_{34} = HIGH; I_{OUT1-4} = 0 A; – 40 °C < T_j < 150 °C; unless otherwise specified

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
Input Interface						
Logic Inputs IN1; IN2; IN3; IN4						
H-input voltage	V_{IH}	–	2.0	3.0	V	–
L-input voltage	V_{IL}	1.0	1.5	–	V	–
Hysteresis of input voltage	V_{IHY}	–	0.5	–	V	–
H-input current	I_{IH}	– 2	–	10	µA	V_I = 5 V
L-input current	I_{IL}	– 100	– 20	– 5	µA	V_I = 0 V
Logic Inputs INH_{12}; INH_{34}						
H-input voltage	V_{IH}	–	2.7	3.5	V	–
L-input voltage	V_{IL}	1.0	2.0	–	V	–
Hysteresis of input voltage	V_{IHY}	–	0.7	–	V	–
H-input current	I_{IH}	–	100	250	µA	V_{INH} = 5 V
L-input current	I_{IL}	– 10	–	10	µA	V_{INH} = 0 V
Error-Flags EF_{12}; EF_{34}						
L-output voltage level	V_{EFL}	–	0.2	0.4	V	I_{EF} = 2 mA
Leakage current	I_{EFLK}	–	–	10	µA	0 V < V_{EF} < 7 V

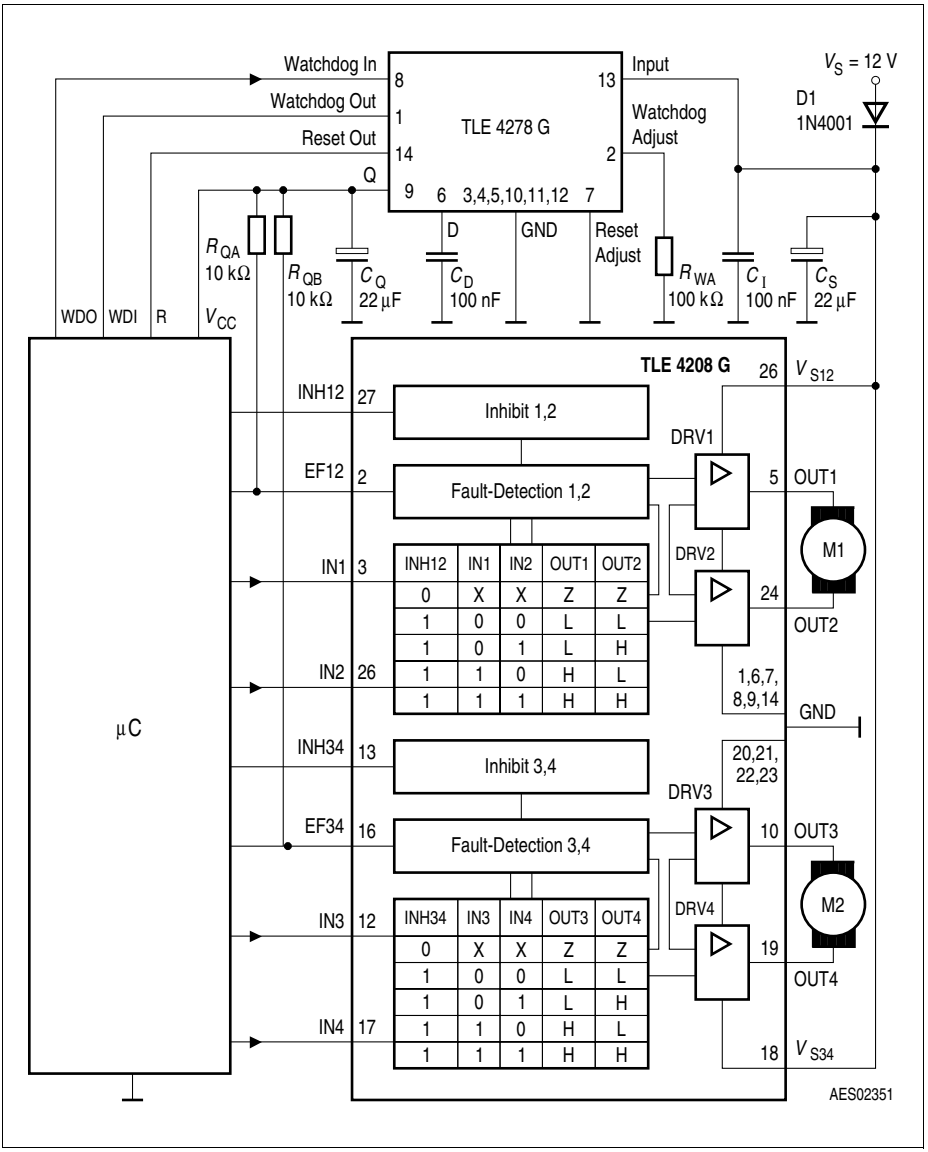
Electrical Characteristics (cont'd)

8 V < V_{S12} = V_{S34} < 18 V; INH_{12} = INH_{34} = HIGH; I_{OUT1-4} = 0 A; – 40 °C < T_j < 150 °C; unless otherwise specified

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
Thermal Shutdown						
Thermal shutdown junction temperature	T_{jSD}	150	175	200	°C	–
Thermal switch-on junction temperature	T_{jSO}	120	–	170	°C	–
Temperature hysteresis	ΔT	–	30	–	K	–

1) Guaranteed by design.

Note: The listed characteristics are ensured over the operating range of the integrated circuit. Typical characteristics specify mean values expected over the production spread. If not otherwise specified, typical characteristics apply at T_A = 25°C and the given supply voltage.



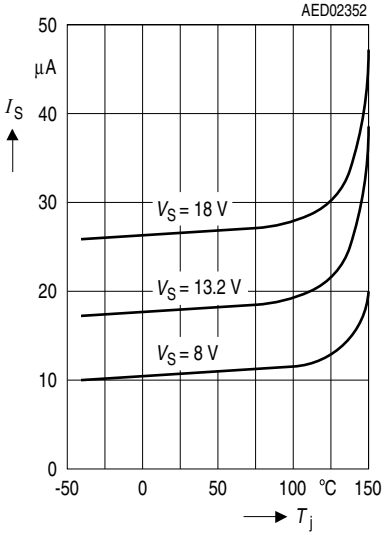
INH12	IN1	IN2	OUT1	OUT2
0	X	X	Z	Z
1	0	0	L	L
1	0	1	L	H
1	1	0	H	L
1	1	1	H	H

INH34	IN3	IN4	OUT3	OUT4
0	X	X	Z	Z
1	0	0	L	L
1	0	1	L	H
1	1	0	H	L
1	1	1	H	H

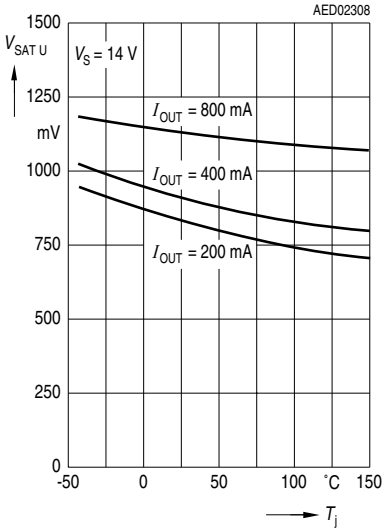
Figure 3 Application Circuit 1 (Device is Used as Dual-Full-Bridge-Driver)

Diagrams

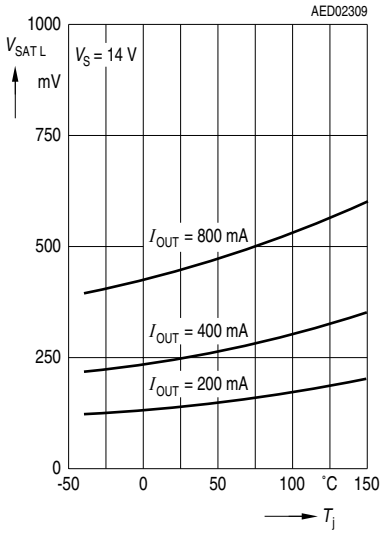
Quiescent current I_S over Temperature



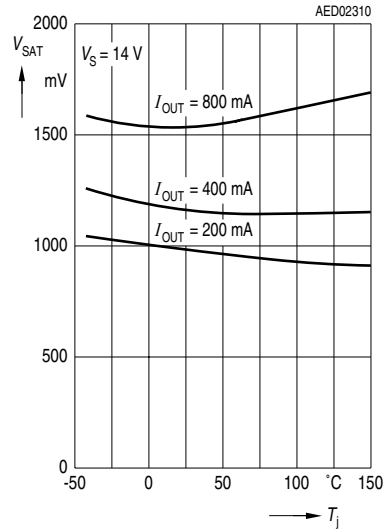
Saturation Voltage of Source $V_{SAT\,U}$ over Temperature



Saturation Voltage of Sink $V_{SAT\,L}$ over Temperature



Total Drop at outputs V_{SAT} over Temperature



Package Outlines

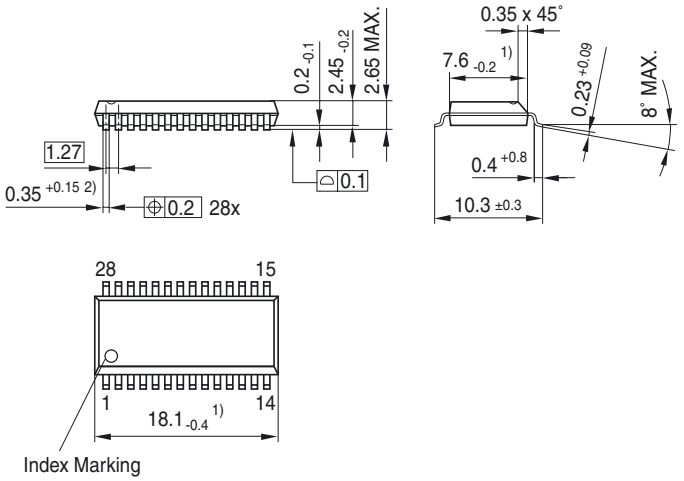


Figure 4 **PG-DSO-28-24** (Plastic Dual Small Outline Transistor)

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

You can find all of our packages, sorts of packing and others in our Infineon Internet Page “Products”: **http://www.infineon.com/products**.

SMD = Surface Mounted Device

Dimensions in mm

Version	Date	Changes
Rev. 1.1	2008-02-04	Initial version of RoHS-compliant derivate of TLE4208G Page 1: added AEC certified statement Page 1 and 13: added RoHS compliance statement and Green product feature Page 1 and 3: Editorial change: deleted "fully" (The term "fully protected" often leads to misunderstandings as it is unclear with respect to which parameters). Page 1 and 14: Package changed to RoHS compliant version Page 15: added Revision History, updated Legal Disclaimer

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